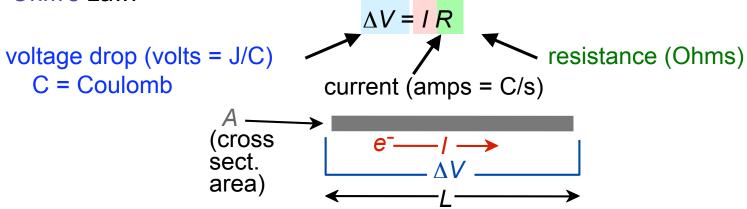
Electrical conductivity

• Ohm's Law:



- Resistivity, ρ and Conductivity, σ:
 - -- geometry-independent forms of Ohm's Law
 - -- Resistivity is a material property & is independent of sample

Conductivity: comparison

• Room T values $(Ohm-m)^{-1} = (\Omega - m)^{-1}$

METALS	conductors	CERAMICS
··- · · · · · ·	CONTACTOR	

Copper
$$6.0 \times 10^7$$

Iron
$$1.0 \times 10^{7}$$

<10-13

Silicon
$$4 \times 10^{-4}$$

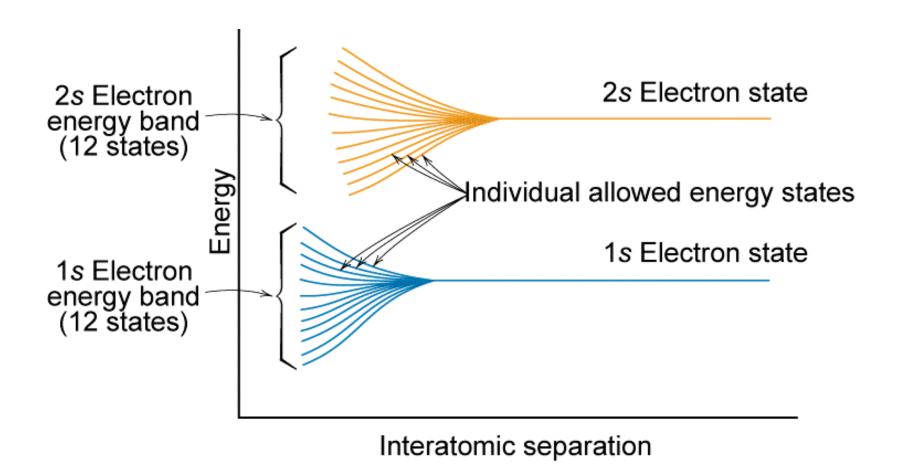
POLYMERS

insulators

semiconductors

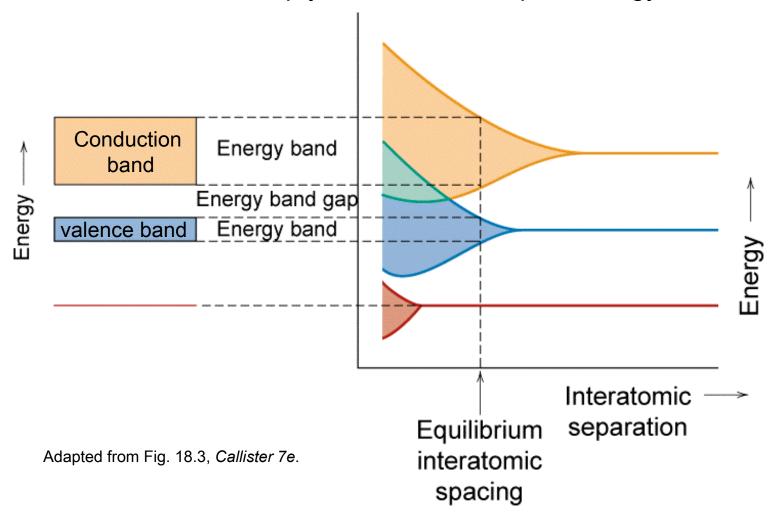
Selected values from Tables 18.1, 18.3, and 18.4, Callister 7e.

Electronic band structure

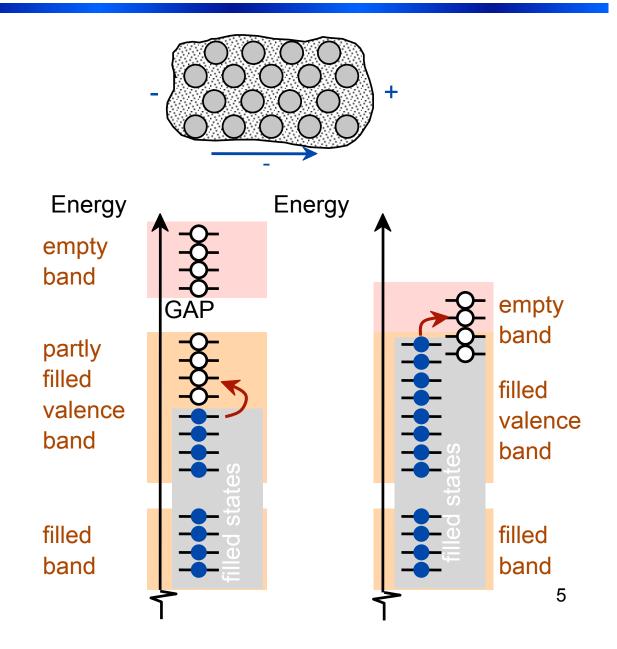


Electronic band structure

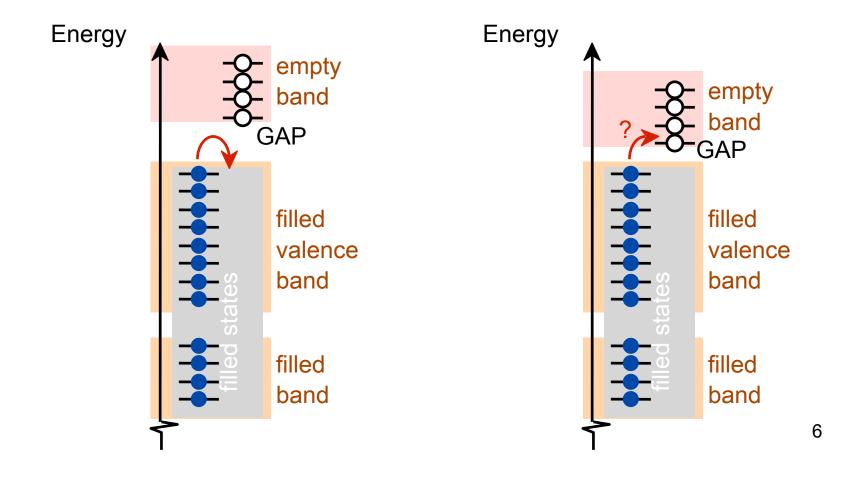
- •Valence band filled highest occupied energy levels
- Conduction band empty lowest unoccupied energy levels



Conduction and electron transport

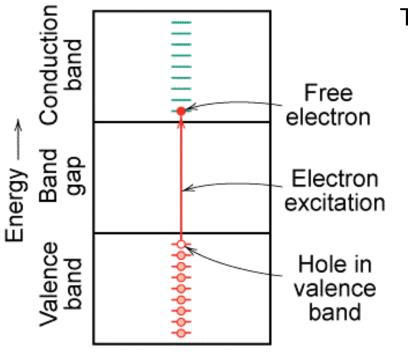


Energy states: Insulators & semiconductors



Charge carriers

Adapted from Fig. 18.6 (b), Callister 7e.



Two charge carrying mechanisms

Electron – negative chargeHole – equal & oppositepositive charge

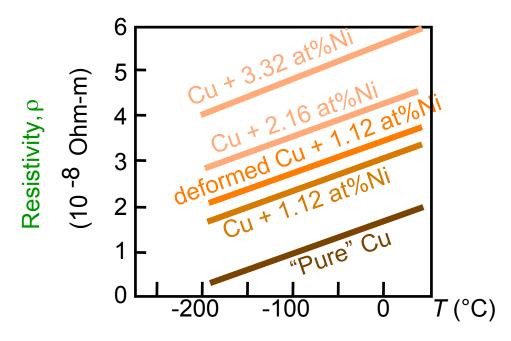
Move at different speeds - drift velocity

Higher temp. promotes more electrons into the conduction band

∴ $\sigma \uparrow$ as $T \uparrow$

Electrons scattered by impurities, grain boundaries, etc.

Charge carriers

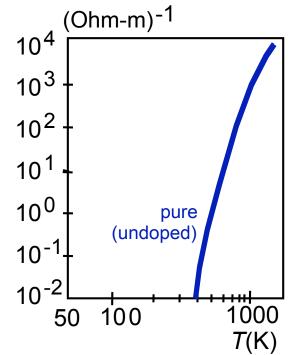


Adapted from Fig. 18.8, *Callister 7e*. (Fig. 18.8 adapted from J.O. Linde, *Ann. Physik* **5**, p. 219 (1932); and C.A. Wert and R.M. Thomson, *Physics of Solids*, 2nd ed., McGraw-Hill Book Company, New York, 1970.)

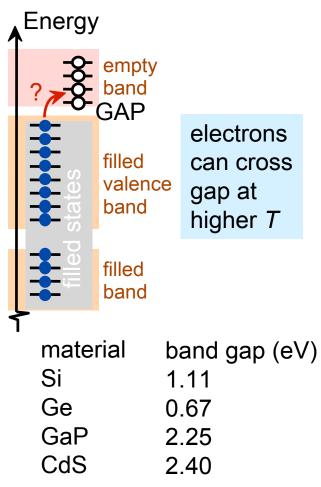
Pure semiconductors: Conductivity vs T

- Data for Pure Silicon:
 - -- σ increases with T
 - -- opposite to metals

electrical conductivity, σ



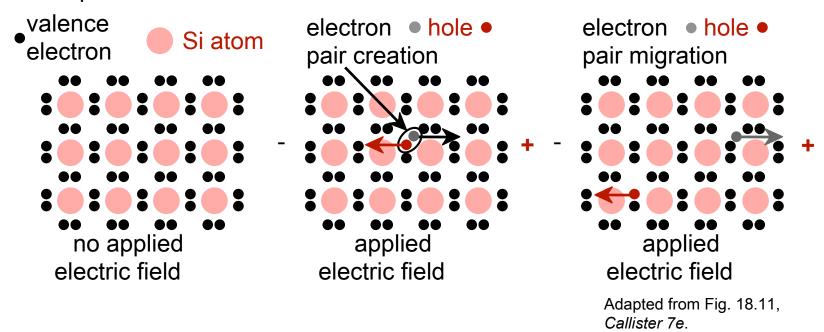
Adapted from Fig. 19.15, *Callister 5e.* (Fig. 19.15 adapted from G.L. Pearson and J. Bardeen, *Phys. Rev.* **75**, p. 865, 1949.)



Selected values from Table 18.3, *Callister 7e*.

Conduction in terms of electron and hole migration

Concept of electrons and holes:



Intrinsic vs extrinsic conduction

Intrinsic:

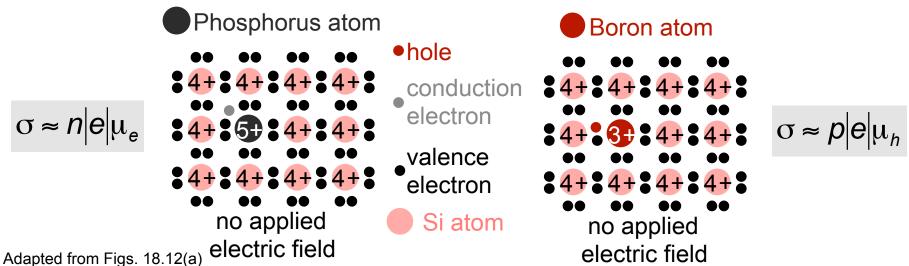
```
# electrons = # holes (n = p) --case for pure Si
```

- Extrinsic:
 - *--n* ≠ *p*

& 18.14(a), Callister 7e.

- --occurs when impurities are added with a different # valence electrons than the host (e.g., Si atoms)
- *n*-type Extrinsic: (*n* >> *p*)

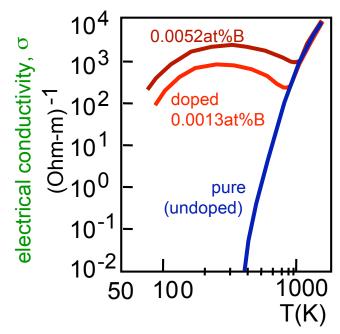
p-type Extrinsic: (p >> n)



11

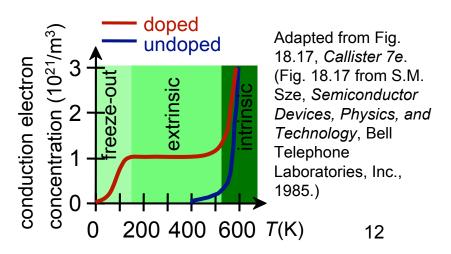
Doped semiconductor: conductivity vs. T

- Data for Doped Silicon:
 - -- σ increases with doping
 - reason: imperfection sites lower the activation energy to produce mobile electrons.



Adapted from Fig. 19.15, *Callister 5e.* (Fig. 19.15 adapted from G.L. Pearson and J. Bardeen, *Phys. Rev.* **75**, p. 865, 1949.)

- Comparison: intrinsic vs extrinsic conduction...
 - extrinsic doping level:
 10²¹/m³ of a *n*-type donor impurity (such as P).
 - -- for *T* < 100 K: "freeze-out", thermal energy insufficient to excite electrons.
 - -- for 150 K < T < 450 K: "extrinsic"
 - -- for *T* >> 450 K: "intrinsic"



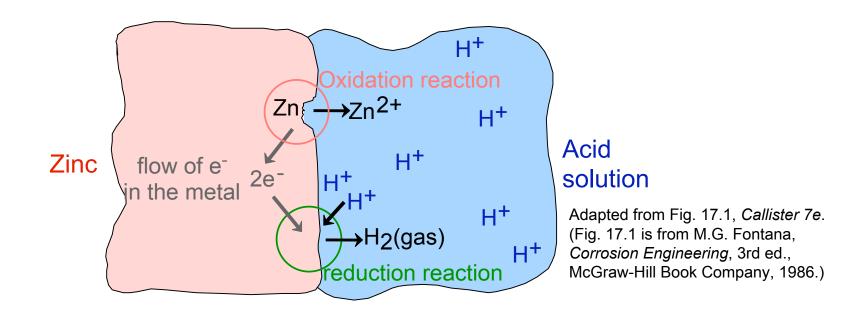
Doped semiconductor: conductivity vs. T

Intrinsic Conductivity

$$\sigma = n|e|\mu_e + p|e|\mu_e$$

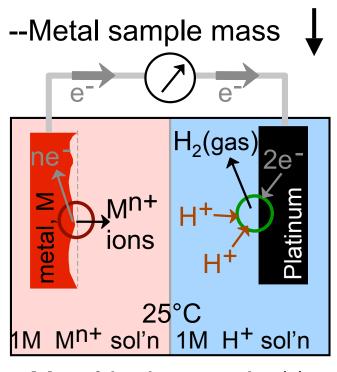
Corrosion of zinc in acid

- Two reactions are necessary:
 - -- oxidation reaction:
 - -- reduction reaction:

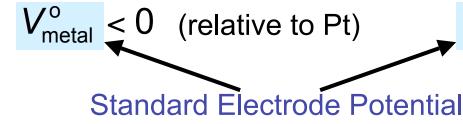


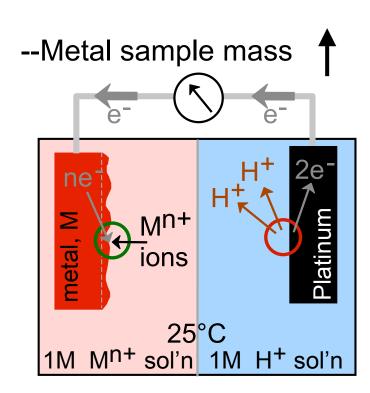
Standard hydrogen (EMF) test

Two outcomes:



--Metal is the anode (-)



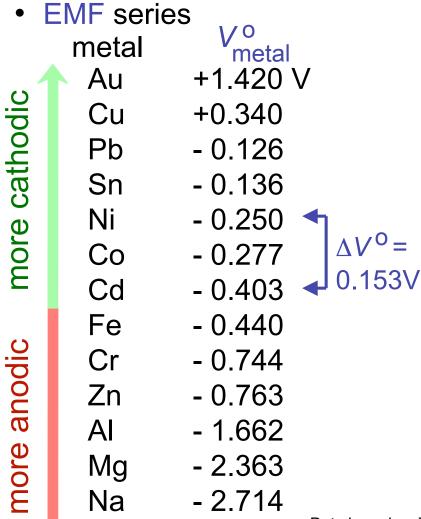


--Metal is the cathode (+)

$$V_{\text{metal}}^{\text{o}} > 0$$
 (relative to Pt)

Adapted from Fig. 17.2, Callister 7e.

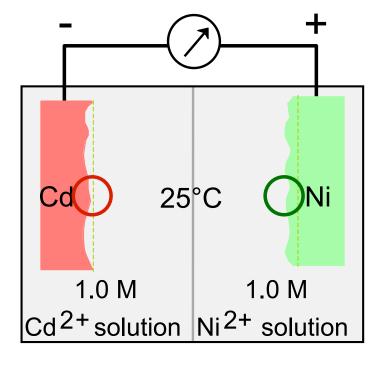
Standard EMF series



- 2.924

K

- Metal with smaller V_{metal} corrodes.
- Ex: Cd-Ni cell

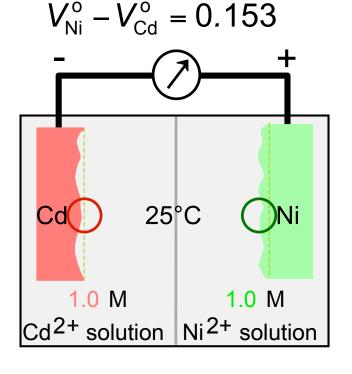


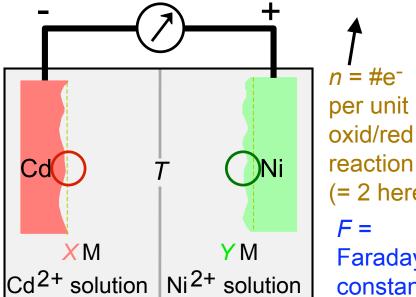
Data based on Table 17.1, *Callister 7e*.

Adapted from Fig. 17.2, Callister 7e.

Effect of solution concentration

• Ex: Cd-Ni cell with Ex: Cd-Ni cell with standard 1 M solutions





 Reduce V_{Ni} - V_{Cd} by --increasing X --decreasing Y

(= 2 here) F= Faraday's constant = 96,500 C/mol.

Galvanic series

Ranks the reactivity of metals/alloys in seawater

more cathodic (inert)

more anodic (active)

Platinum

Gold

Graphite

Titanium

Silver

316 Stainless Steel

Nickel (passive)

Copper

Nickel (active)

Tin

Lead

316 Stainless Steel

Iron/Steel

Aluminum Alloys

Cadmium

Zinc

Magnesium

Based on Table 17.2, Callister 7e. (Source of Table 17.2 is M.G. Fontana, Corrosion Engineering, 3rd ed., McGraw-Hill Book Company, 1986.)

Forms of corrosion

- Uniform Attack
 Oxidation & reduction
 occur uniformly over
 surface
- Selective Leaching
 Preferred corrosion of one element/constituent (e.g., Zn from brass (Cu-Zn)).
 - Intergranular
 Corrosion along
 grain boundaries,
 often where special
 phases exist.

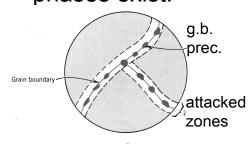


Fig. 17.18, Callister 7e.

Stress corrosion

Stress & corrosion work together at crack tips.

Forms of corrosion

Galvanic

Dissimilar metals are physically joined. The more anodic one corrodes.(see Table 17.2) Zn & Mg very anodic.

Erosion-corrosion

Break down of passivating layer by erosion (pipe elbows).

Pitting

Downward propagation of small pits & holes.

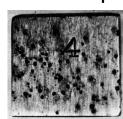


Fig. 17.17, Callister 7e. (Fig. 17.17 from M.G. Fontana, Corrosion Engineering, 3rd ed., McGraw-Hill Book Company, 1986.)

• Crevice Between two pieces of the same metal.

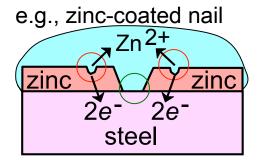


Fig. 17.15, *Callister 7e*. (Fig. 17.15 is courtesy LaQue Center for Corrosion Technology, Inc.)

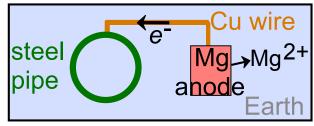
Controlling corrosion

- Self-protecting metals!
 - -- Metal ions combine with O to form a thin, adhering oxide layer that slows corrosion. Metal (e.g., Al, stainless steel)
- Reduce T (slows kinetics of oxidation and reduction)
- Add inhibitors
 - -- Slow oxidation/reduction reactions by removing reactants (e.g., remove O₂ gas by reacting it w/an inhibitor).
 - -- Slow oxidation reaction by attaching species to the surface (e.g., paint it!).
- Cathodic (or sacrificial) protection
 - -- Attach a more anodic material to the one to be protected.

Adapted from Fig. 17.23, Callister 7e.



e.g., Mg Anode



Adapted from Fig. 17.22(a), *Callister 7e.* (Fig. 17.22(a) is from M.G. Fontana, *Corrosion Engineering*, 3rd ed., McGraw-Hill Book Co., 1986.)

Metal oxide